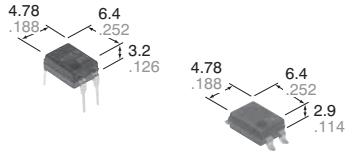


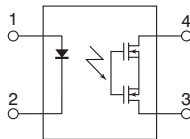
Normally closed DIP4-pin
economic type with
reinforced insulation

PhotoMOS[®]
GU-E 1 Form B
(AQY410EH)



CAD Data

mm inch

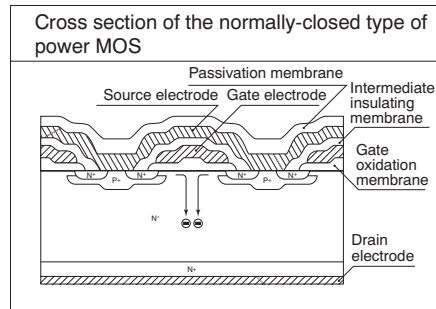


FEATURES

1. High cost-performance type of PhotoMOS relay 1 Form B output

2. Low on-resistance

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



3. Reinforced insulation of 5,000 V

More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

4. Controls low-level analog signals

PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

5. High sensitivity and low on-resistance

Can control max. 0.55 A load current with 5 mA input current.

Low on-resistance of typ. 1Ω (AQY412EH).

6. Low-level off-state leakage current

TYPICAL APPLICATIONS

- Power supply
- Measuring equipment
- Security equipment
- Modem
- Telephone equipment
- Electricity, plant equipment
- Sensing equipment

TYPES

Type	I/O isolation voltage	Output rating*		Package	Part No.				Packing quantity	
					Through hole terminal	Surface-mount terminal				
		Load voltage	Load current			Tube packing style	Tape and reel packing style		Tube	Tape and reel
							Picked from the 1/2-pin side	Picked from the 3/4-pin side		
AC/DC dual use	Reinforced 5,000 V	60 V	550 mA	DIP4-pin	AQY412EH		AQY412EHA	AQY412EHAX		
		350 V	130 mA		AQY410EH	AQY410EHA	AQY410EHAX	AQY410EHAZ	1 batch contains: 1,000 pcs.	
		400 V	120 mA		AQY414EH	AQY414EHA	AQY414EHAX	AQY414EHAZ		

*Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the part number "AQY", the surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay. (Ex. the label for product number AQY412EHAX is 412EH.)

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

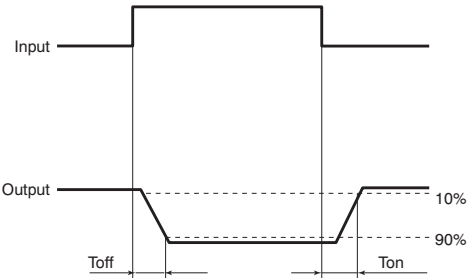
Item		Symbol	AQY412EH(A)	AQY410EH(A)	AQY414EH(A)	Remarks
Input	LED forward current	I _F	50 mA			
	LED reverse voltage	V _R	5 V			
	Peak forward current	I _{FP}	1 A			f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P _{in}	75 mW			
Output	Load voltage (peak AC)	V _L	60 V	350 V	400 V	
	Continuous load current	I _L	0.55 A	0.13 A	0.12 A	Peak AC, DC
	Peak load current	I _{peak}	1.5 A	0.4 A	0.3 A	100 ms (1 shot), V _L = DC
	Power dissipation	P _{out}	500 mW			
Total power dissipation		P _T	550 mW			
I/O isolation voltage		V _{iso}	5,000 V AC			
Temperature limits	Operating	T _{opr}	-40°C to +85°C -40°F to +185°F			Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F			

GU-E 1 Form B (AQY410EH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQY412EH(A)	AQY410EH(A)	AQY414EH(A)	Condition
Input	LED operate (OFF) current	Typical	I _{Foff}	1.4 mA			I _L =Max.
		Maximum		3.0 mA			
	LED reverse (ON) current	Minimum	I _{Fon}	0.4 mA			I _L =Max.
		Typical		1.3 mA			
	LED dropout voltage	Typical	V _F	1.25 (1.14 V at I _F = 5 mA)			I _F = 50 mA
		Maximum		1.5 V			
Output	On resistance	Typical	R _{on}	1Ω	18Ω	26Ω	I _F = 0 mA I _L = Max. Within 1 s on time
		Maximum		2.5Ω	25Ω	35Ω	
	Off state leakage current	Maximum	I _{Leak}	10μA			I _F = 5 mA V _L = Max.
Transfer characteristics	Operate (OFF) time*	Typical	T _{off}	3.0 ms	1.0 ms	0.8 ms	I _F = 0 mA → 5 mA I _L = Max.
		Maximum		10.0 ms	3.0 ms		
	Reverse (ON) time*	Typical	T _{on}	0.2 ms	0.3 ms	0.2 ms	I _F = 5 mA → 0 mA I _L = Max.
		Maximum		1.0 ms			
	I/O capacitance	Typical	C _{iso}	0.8 pF			f =1MHz V _B = 0 V
		Maximum		1.5 pF			
Initial I/O isolation resistance		Minimum	R _{iso}	1,000MΩ			500 V DC

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I _F	5 to 10	mA

- Dimensions
- Schematic and Wiring Diagrams
- Cautions for Use

■ These products are not designed for automotive use.

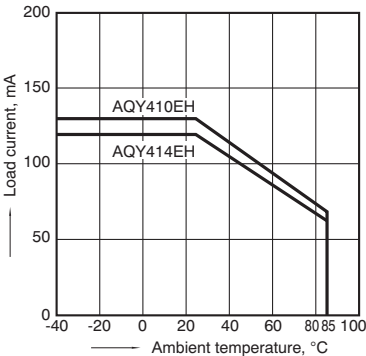
If you are considering to use these products for automotive applications, please contact your local Panasonic technical representative.

Please refer to our information on [PhotoMOS Relays for Automotive Applications](#).

REFERENCE DATA

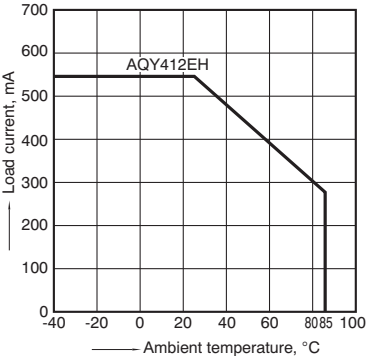
1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



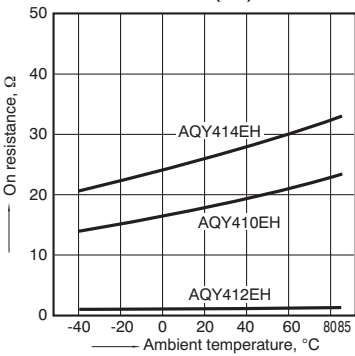
1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F



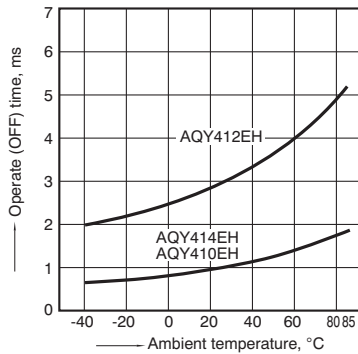
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4;
LED current: 0 mA; Load voltage: Max.(DC);
Continuous load current: Max. (DC)



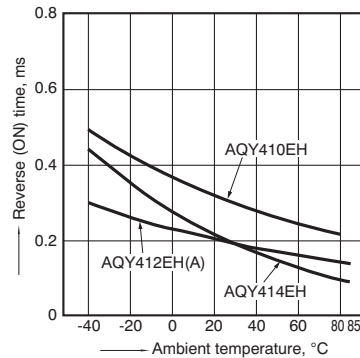
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



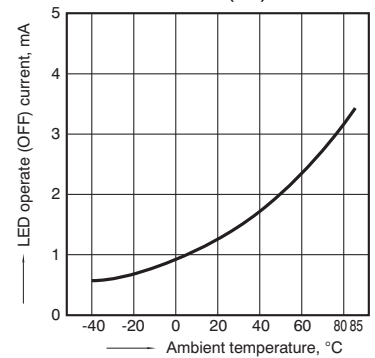
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



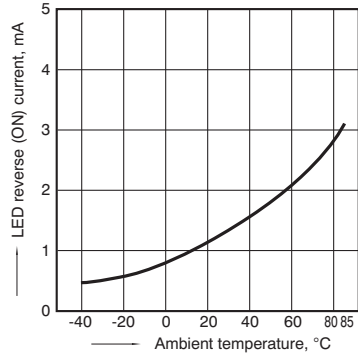
5. LED operate (OFF) current vs. ambient temperature characteristics

Sample: All types;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



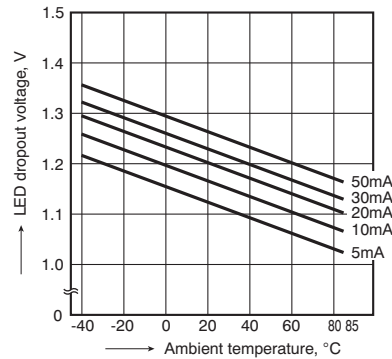
6. LED reverse (ON) current vs. ambient temperature characteristics

Sample: All types;
Load voltage: Max. (DC);
Continuous load current: Max. (DC)



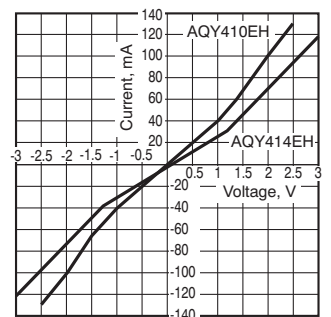
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



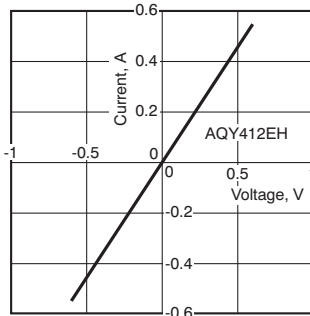
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



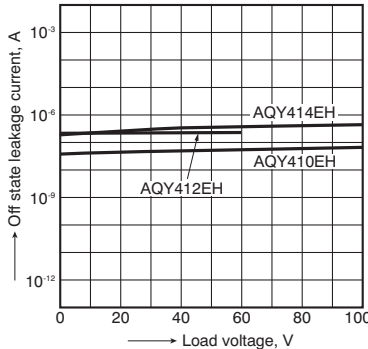
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



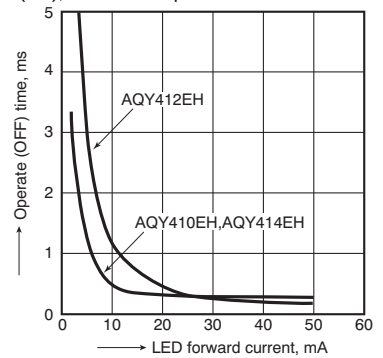
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4;
Ambient temperature: 25°C 77°F



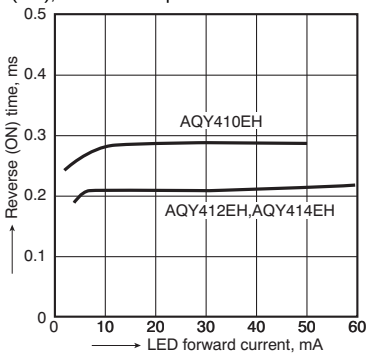
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
Load voltage: Max. (DC); Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4;
Load voltage: Max. (DC); Continuous load current: Max. (DC);
Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F

